NSN 5961-01-203-1176

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View Online at https://aerobasegroup.com/nsn/5961-01-203-1176 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Terminal Length:** 0.312 inches **Overall Height:** 0.360 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage/static/emitter open and -7.0 emitter to base voltage, static, collector open and -80.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** -20.00 amperes source cutoff current and -0.50 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 81349-mil-s-19500/505 government specification Shelf Life:

Demilitarization: Voc. domil/mli

Unit Of Measure:

N/a

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